

General Description

The MAX14756/MAX14757/MAX14758 are analog switches with a low on-resistance of 10Ω (max) that conduct equally well in both directions. All devices have a rail-to-rail analog-signal range. They operate with a single +10V to +70V supply in unipolar applications or ±35V dual supplies in bipolar applications. The bipolar supplies can be offset and do not have to be symmetrical.

The MAX14756 is a guad normally closed (NC) singlepole/single-throw (SPST) switch, the MAX14757 is a quad normally open (NO) SPST switch, and the MAX14758 has two NO and two NC SPST switches. These switches have 5Ω (typ) on-resistances and low on-leakage currents of 0.01nA (typ). The on-resistance flatness is 0.004Ω (typ).

The devices are suitable for a multitude of analog signal routing and switching applications. They are specified over an extended temperature range of -40°C to +85°C, but can be operated up to +125°C with elevated leakage currents.

Applications

Industrial Control Systems

Instrumentation

Battery Management

Environmental Control Systems

Medical Systems

ATE System

Audio Signal Routing/Switching

Automotive

Features

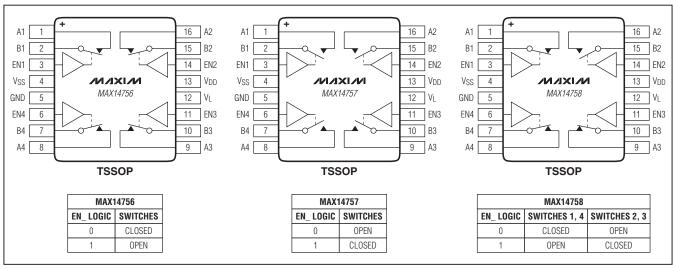
- ♦ Single-Supply Operation from +10V to +70V
- ♦ Bipolar-Supply Operation Up to ±35V
- ♦ On-Resistance of 10Ω (max)
- ♦ Ron Flatness of 0.004Ω (typ)
- ◆ 2.5nA (max) Off-Leakage Currents at +85°C
- Overvoltage/Undervoltage Clamping Through **Protection Diodes**
- ♦ 500µA (typ) Supply Current
- ◆ TSSOP 16-Pin Package
- ◆ -40°C to +85°C Ambient Temperature Range
- ◆ Functionally Compatible to DG411, DG412, and **DG413**
- ◆ Functionally Operational Up to +125°C

Ordering Information

PART	FUNCTION	TEMP RANGE	PIN- PACKAGE
MAX14756EUE+	Quad NC SPST	-40°C to +85°C	16 TSSOP
MAX14757EUE+	Quad NO SPST	-40°C to +85°C	16 TSSOP
MAX14758EUE+	Dual NO + NC SPST	-40°C to +85°C	16 TSSOP

⁺Denotes a lead(Pb)-free/RoHS-compliant package.

Functional Diagrams



MIXIM

Maxim Integrated Products 1

ABSOLUTE MAXIMUM RATINGS

VDD to VSS	0.3V to +72V
Vss to GND	36V to +0.3V
VL, EN_ to GND0.3V to the les	ser of (+12V, V _{DD} + 0.3V)
A_, B_ to VSS0.3	V to (V _{DD} + 2V) or 100mA
	(whichever occurs first)
Continuous Current into A_, B	±100mA

Continuous Power Dissipation ($T_A = +70$ °C)	
TSSOP (derate 11.1mW/°C above +70°C)	889mW
Operating Temperature Range	40°C to +85°C
Storage Temperature Range	65°C to +150°C
Junction Temperature	+150°C
Lead Temperature (soldering, 10s)	+300°C
Soldering Temperature (reflow)	+260°C

PACKAGE THERMAL CHARACTERISTICS (Note 1)

TSSOP

Junction-to-Ambient Thermal Resistance (θ_{JA})......90°C/W Junction-to-Case Thermal Resistance (θ_{JC})......27°C/W

Note 1: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to www.maxim-ic.com/thermal-tutorial.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—DUAL SUPPLIES

 $(V_{DD} = +35V, V_{SS} = -35V, V_{GND} = 0V, V_{L} = +3.3V, T_{A} = -40^{\circ}C$ to $+85^{\circ}C$, unless otherwise noted. Typical values are at $T_{A} = +25^{\circ}C$.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
POWER SUPPLY						
V _{DD} Supply-Voltage Range	VDD		+10		+35	V
Vss Supply-Voltage Range	Vss		-10		-35	V
V _L Logic Supply-Voltage Range	VL		+1.6		+11	V
V _{DD} Supply Current	IDD(OFF)	V_{EN} to switch off state, V_{A} , V_{B} = +20V		200	450	
VDD Supply Current	IDD(ON)	V _{EN} _ to switch on state, V _A _, V _B _ = +20V		500	800	μΑ
Vss Supply Current	ISS(OFF)	V_{EN} to switch off state, V_{A} , V_{B} = +20V		200	450	
VSS Supply Current	ISS(ON)	VEN_ to switch on state, VA_, VB_ = +20V		500	800	μΑ
V _L Current	IL	V _L = +11V, V _{EN1} = V _{EN2} = V _{EN3} = V _{EN4} = (0.25 x V _L) or (0.75 x V _L)			0.4	mA
SWITCH						
Analog-Signal Range	VA_, VB_	Figure 1	Vss		V_{DD}	V
Current Through Switch	I _{A_,} I _{B_}	VA_, VB_ = +20V	-50		+50	mA
On-Resistance	Ron	I _{A_} , I _{B_} = 10mA, V _{A_} , V _{B_} = ±20V, Figure 1		5	10	Ω
On-Resistance Matching Between Channels	ΔRon	I _{A_} , I _{B_} = 10mA, V _{A_} , V _{B_} = ±20V, 0V (Note 2)		0.3	0.5	Ω
On-Resistance Flatness	RFLAT(ON)	IA_, IB_ = 10mA, VA_, VB_ = ±20V		0.004		Ω
		V _B _ = ±20V, V _A _= unconnected, Figure 2	-5		+5	
On-Leakage Current	IA/B_(ON)	VB_ = ±20V, VA_ = unconnected, TA = +25°C, Figure 2		0.01		nA
		V _B _ = ±20V, V _A _ = -20V, Figure 3	-2.5		+2.5	
Off-Leakage Current	I _{A/B_} (OFF)	V _B _ = ±20V, V _A _ = -20V, T _A = +25°C, Figure 3		0.01		nA

ELECTRICAL CHARACTERISTICS—DUAL SUPPLIES (continued)

(VDD = +35V, VSS = -35V, VGND = 0V, VL = +3.3V, TA = -40°C to +85°C, unless otherwise noted. Typical values are at TA = +25°C.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
LOGIC (EN1, EN2, EN3, EN4)						
Input-Voltage Low	VIL				0.25 x V _L	V
Input-Voltage High	VIH		0.75 x VL			V
Input Leakage Current		V _{EN_} = 0V or V _L	-1		+1	μΑ
DYNAMIC CHARACTERISTICS						
V _{DD} /V _{SS} Power-On Time		$R_L = 10k\Omega$		1		μs
Enable Turn-On Time	ton	V_{A} , V_{B} = ±10V, R_L = 10k Ω , Figure 4		35	60	μs
Enable Turn-Off Time	toff	$V_{A_{-}}$, $V_{B_{-}}$ = ±10V, R_{L} = 10k Ω , Figure 4		2	3	μs
Off-Isolation	Viso	VA_{-} , VB_{-} = 1V RMS, f = 100kHz, RL = 1k Ω , CL = 15pF, Figure 5		65		dB
Crosstalk	VCT	$R_S = R_L = 1k\Omega$, Figure 6		96		dB
-3dB Bandwidth	BW	$R_S = 50\Omega$, $R_L = 1k\Omega$, Figure 7		145		MHz
Total Harmonic Distortion Plus Noise	THD+N	$R_S = R_L = 1k\Omega$, $f = 20Hz$ to $20kHz$		0.001		%
Charge Injection	Q	A_, B_ = GND, CL = 1nF, Figure 8		580		рС
Switch-On Capacitance	CIN	V _{DD} = +50V, V _{SS} = 0V, V _A , V _B = +4V, f = 1MHz		40		рF
Switch-Off Capacitance	CIN	V _{DD} = +50V, V _{SS} = 0V, V _A , V _B = +4V, f = 1MHz		35		pF

DC ELECTRICAL CHARACTERISTICS—SINGLE SUPPLY

 $(V_{DD} = +70V, V_{SS} = V_{GND} = 0V, V_{L} = +3.3V, T_{A} = -40^{\circ}C$ to $+85^{\circ}C$, unless otherwise noted. Typical values are at $T_{A} = +25^{\circ}C$.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
POWER SUPPLY					-	
V _{DD} Supply-Voltage Range	V _{DD}		+10		+70	V
SWITCH						
On-Resistance	Ron	I _A _ = 10mA, V _A _, V _B _= +20V, Figure 1		5	10	Ω
On-Resistance Matching Between Channels	ΔR _{ON}	I _{A_} , I _{B_} = 10mA, V _{A_} , V _{B_} = +70V, 0V (Note 2)		0.3	0.5	Ω
Off-Leakage Current	IA/B_(OFF)	V _B ₌ +40V, V _A ₌ +10V, Figure 3	-2.5		+2.5	nA

Note 2: Guaranteed by design; not production tested.

Note 3: All parameters in single-supply operation are expected to be the same as in dual-supply operation.

Test Circuits/Timing Diagrams

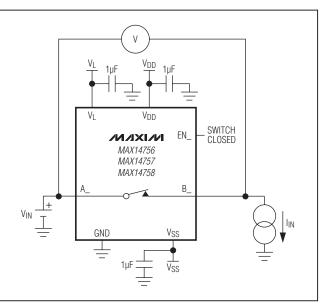


Figure 1. On-Resistance Measurement

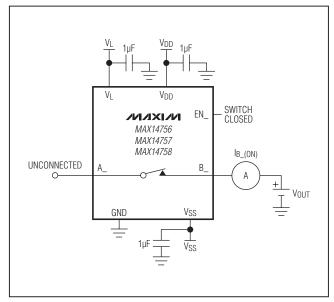


Figure 2. On-Leakage Current

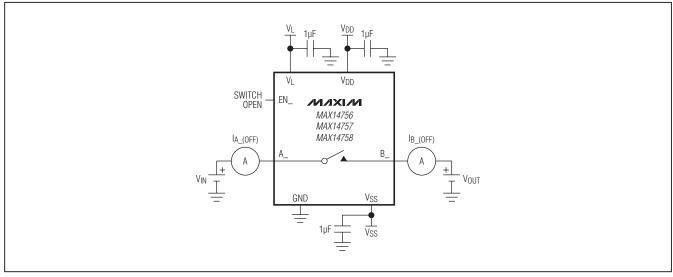


Figure 3. Off-Leakage Current

Test Circuits/Timing Diagrams (continued)

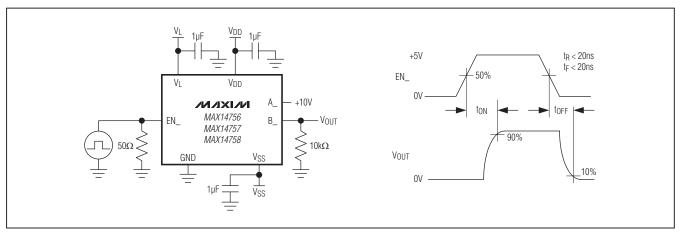


Figure 4. Enable Switching Time

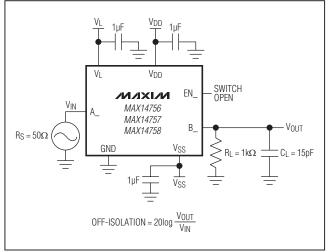


Figure 5. Off-Isolation

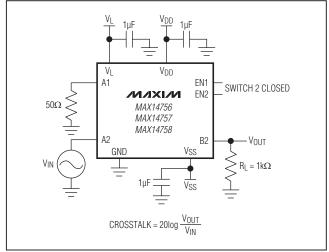


Figure 6. Crosstalk

Test Circuits/Timing Diagrams (continued)

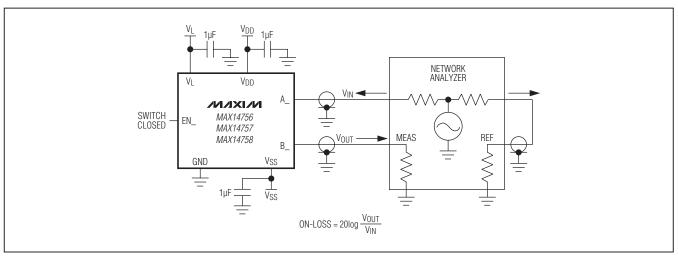


Figure 7. Frequency Response

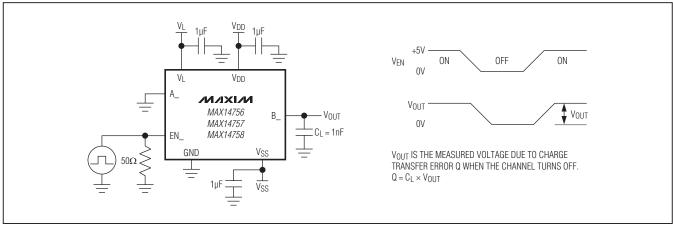
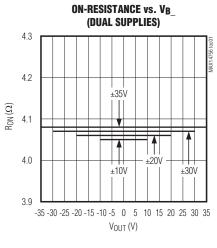
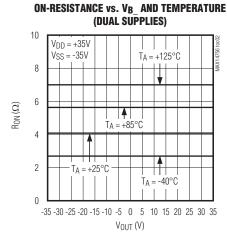


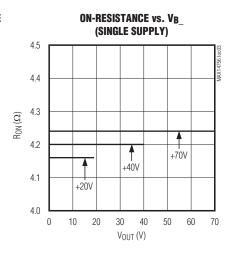
Figure 8. Charge Injection

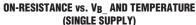
Typical Operating Characteristics

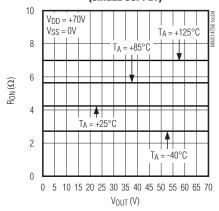
 $(T_A = +25^{\circ}C, V_L = +3.3V, \text{ unless otherwise noted.})$

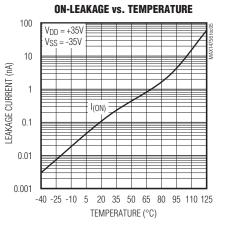


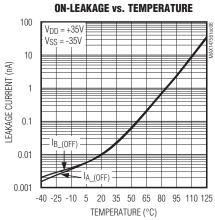




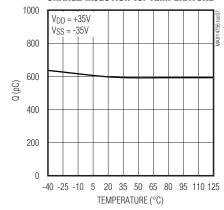


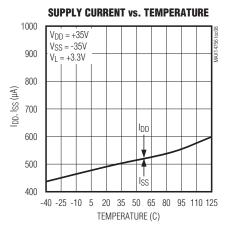


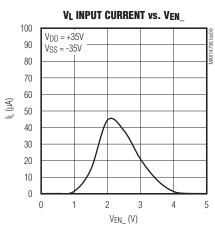




CHARGE INJECTION vs. TEMPERATURE

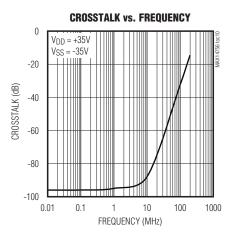


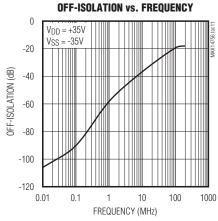


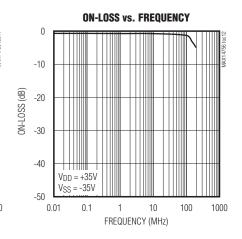


Typical Operating Characteristics (continued)

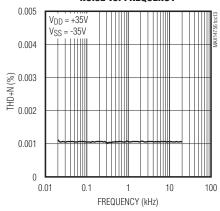
 $(T_A = +25$ °C, $V_L = +3.3$ V, unless otherwise noted.)

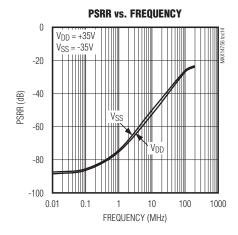




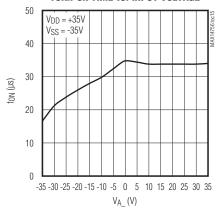


TOTAL HARMONIC DISTORTION PLUS NOISE vs. FREQUENCY

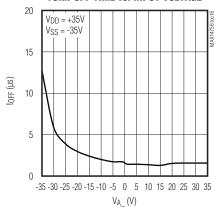




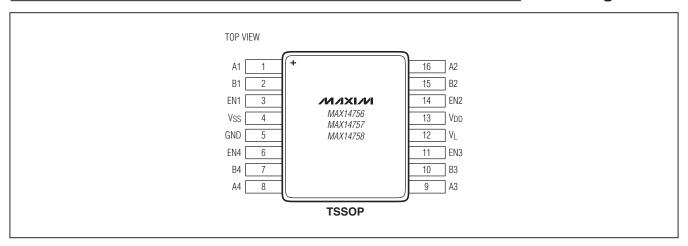
TURN-ON TIME vs. INPUT VOLTAGE







Pin Configuration



Pin Description

PIN	NAME	FUNCTION
1	A1	Terminal A of Switch 1
2	B1	Terminal B of Switch 1
3	EN1	Enable Input of Switch 1. When EN1 is driven high, the switch's state (NO/NC) changes (see Tables 1, 2, and 3).
4	V _{SS}	Negative Supply Voltage. Bypass VSS to GND with a 1µF ceramic capacitor (100V rated) as close as possible to the pin.
5	GND	Ground
6	EN4	Enable Input of Switch 4. When EN4 is driven high, the switch's state (NO/NC) changes (see Tables 1, 2, and 3).
7	B4	Terminal B of Switch 4
8	A4	Terminal A of Switch 4
9	АЗ	Terminal A of Switch 3
10	В3	Terminal B of Switch 3
11	EN3	Enable Input of Switch 3. When EN3 is driven high, the switch's state (NO/NC) changes (see Tables 1, 2, and 3).
12	VL	Logic Supply Voltage. Bypass V _L to GND with a 1µF ceramic capacitor as close as possible to the pin.
13	VDD	Positive Supply Voltage. Bypass V _{DD} to GND with a 1µF ceramic capacitor (100V rated) as close as possible to the pin.
14	EN2	Enable Input of Switch 2. When EN2 is driven high, the switch's state (NO/NC) changes (see Tables 1, 2, and 3).
15	B2	Terminal B of Switch 2
16	A2	Terminal A of Switch 2

Detailed Description

The MAX14756/MAX14757/MAX14758 are analog switches with low on-resistance of 10Ω (max) that conduct equally well in both directions. All devices have a rail-to-rail analog-signal range. They operate with a single +70V supply in unipolar applications or $\pm 35 \text{V}$ dual supplies in bipolar applications. The bipolar supplies can be offset and do not have to be symmetrical.

The MAX14756 is a quad NC SPST switch, the MAX14757 is a quad NO SPST switch, and the MAX14758 has two NO and two NC SPST switches. These switches have 5Ω (typ) on-resistances and low on-leakage currents of 5nA (max). The on-resistance flatness is 0.004Ω (typ). These devices are suitable for a multitude of analog-signal routing and switching applications, and are functonally operational up to $+125^{\circ}$ C with increased leakage currents.

Applications Information

Low-Distortion Audio

The MAX14756/MAX14757/MAX14758 switches, having low R_{ON} and very low R_{ON} variation with signal amplitude, are well suited for low-distortion audio applications. The *Typical Operating Characteristics* show Total Harmonic Distortion (THD) vs. Frequency graphs for several signal amplitudes.

Current Through the Switches

The current flowing through every switch must be limited to ± 50 mA for normal operation. If the current exceeds this limit, an internal leakage current flows from the switch to Vss. Larger input currents do not destroy the device, as long as the *Absolute Maximum Ratings* are not exceeded.

Input-Voltage Clamping

For applications that require input voltages beyond the supplies rails, the internal input diodes to VDD and VSS can be used to limit the input voltages. As shown in Figure 9, series resistors can be employed at the inputs to limit the currents flowing into the diodes during undervoltage and overvoltage conditions. Choose the limiting resistors such that the input currents are limited to IIN_(MAX) = 100mA. The values of the current-limit resistors can be calculated as the larger of RLIM+ and RLIM-.

$$\mathsf{R}_{\mathsf{LIM+}} = \frac{\mathsf{V}_{\mathsf{IN}}(\mathsf{MAX}) - \mathsf{V}_{\mathsf{DD}}}{\mathsf{I}_{\mathsf{IN}}(\mathsf{MAX})}$$

$$\mathsf{R}_{\mathsf{LIM-}} = \frac{\mathsf{V}_{\mathsf{SS}} - \mathsf{V}_{\mathsf{IN}}(\mathsf{MIN})}{\mathsf{I}_{\mathsf{IN}}(\mathsf{MAX})}$$

Table 1. MAX14756 Truth Table

LO	GIC	SWI	ТСН
EN1	0	A1/B1	Closed
EN2	0	A2/B2	Closed
EN3	0	A3/B3	Closed
EN4	0	A4/B4	Closed
EN1	1	A1/B1	Open
EN2	1	A2/B2	Open
EN3	1	A3/B3	Open
EN4	1	A4/B4	Open

Table 2. MAX14757 Truth Table

LO	GIC	SWI	тсн
EN1	0	A1/B1	Open
EN2	0	A2/B2	Open
EN3	0	A3/B3	Open
EN4	0	A4/B4	Open
EN1	1	A1/B1	Closed
EN2	1	A2/B2	Closed
EN3	1	A3/B3	Closed
EN4	1	A4/B4	Closed

Table 3. MAX14758 Truth Table

LO	GIC	SWI	тсн
EN1	0	A1/B1	Closed
EN2	0	A2/B2	Open
EN3	0	A3/B3	Open
EN4	0	A4/B4	Closed
EN1	1	A1/B1	Open
EN2	1	A2/B2	Closed
EN3	1	A3/B3	Closed
EN4	1	A4/B4	Open

During an undervoltage or overvoltage condition, the input impedance is equal to RLIM. The additional power dissipation due to the fault currents needs to be calculated. During an overvoltage or undervoltage clamping condition on one switch input, the other switches of the MAX14756/MAX14757/MAX14758 operate normally.

Beyond-the-Rail Input

If input voltages are expected to go beyond the supply voltages, but within the absolute maximum supply voltages of the MAX14756/MAX14757/MAX14758, add two diodes in series with the supplies as shown in Figure 10.

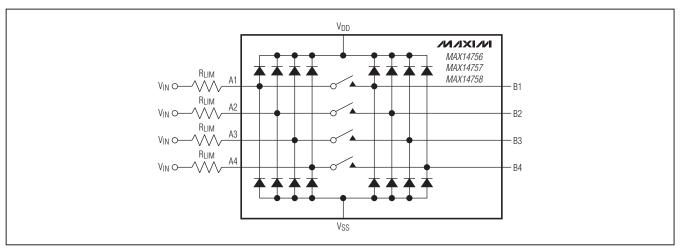


Figure 9. Input Overvoltage and Undervoltage Clamping

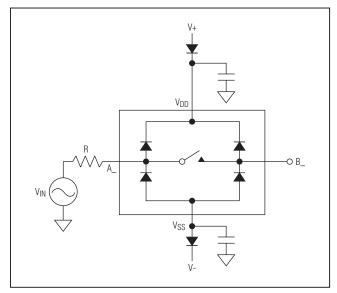


Figure 10. Beyond-the-Rail Application

During undervoltage and overvoltage events, the internal diodes pull VDD/VSS supplies up/down. An advantage of this scheme is that the input impedance is high and currents do not flow though the MAX14756/MAX14757/MAX14758 during overvoltage and undervoltage events. The input voltages must be limited to the voltages specified in the *Absolute Maximum Ratings* section.

Chip Information

PROCESS: BICMOS

Package Information

For the latest package outline information and land patterns (footprints), go to www.maxim-ic.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE	PACKAGE	OUTLINE	LAND
TYPE	CODE	NO.	PATTERN NO.
16 TSSOP	U16+1	<u>21-0066</u>	

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	12/10	Initial release	_

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.